

## Real-Time Clock (RTC)

### Features

- Direct clock/calendar replacement for IBM® AT-compatible computers and other applications
- Functionally compatible with the DS1285
  - Closely matches MC146818A pin configuration
- 2.7–3.6V operation (bq3285L); 4.5–5.5V operation (bq3285E)
- 242 bytes of general nonvolatile storage
- 32.768kHz output for power management
- System wake-up capability—alarm interrupt output active in battery-backup mode
- Less than 0.5μA load under battery operation
- Selectable Intel or Motorola bus timing
- 14 bytes for clock/calendar and control

- BCD or binary format for clock and calendar data
- Calendar in day of the week, day of the month, months, and years, with automatic leap-year adjustment
- Time of day in seconds, minutes, and hours
  - 12- or 24-hour format
  - Optional daylight saving adjustment
- Programmable square wave output
- Three individually maskable interrupt event flags:
  - Periodic rates from 122μs to 500ms
  - Time-of-day alarm once per second to once per day
  - End-of-clock update cycle
- 24-pin plastic DIP, SOIC, or SSOP

### General Description

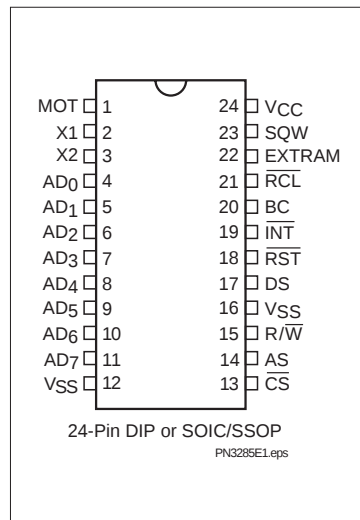
The CMOS bq3285E/L is a low-power microprocessor peripheral providing a time-of-day clock and 100-year calendar with alarm features and battery operation. The bq3285L supports 3V systems. Other bq3285E/L features include three maskable interrupt sources, square-wave output, and 242 bytes of general nonvolatile storage.

A 32.768kHz output is available for sustaining power-management activities. Wake-up capability is provided by an alarm interrupt, which is active in battery-backup mode.

The bq3285E/L write-protects the clock, calendar, and storage registers during power failure. A backup battery then maintains data and operates the clock and calendar.

The bq3285E/L is a fully compatible real-time clock for IBM AT-compatible computers and other applications. The only external components are a 32.768kHz crystal and a backup battery.

### Pin Connections

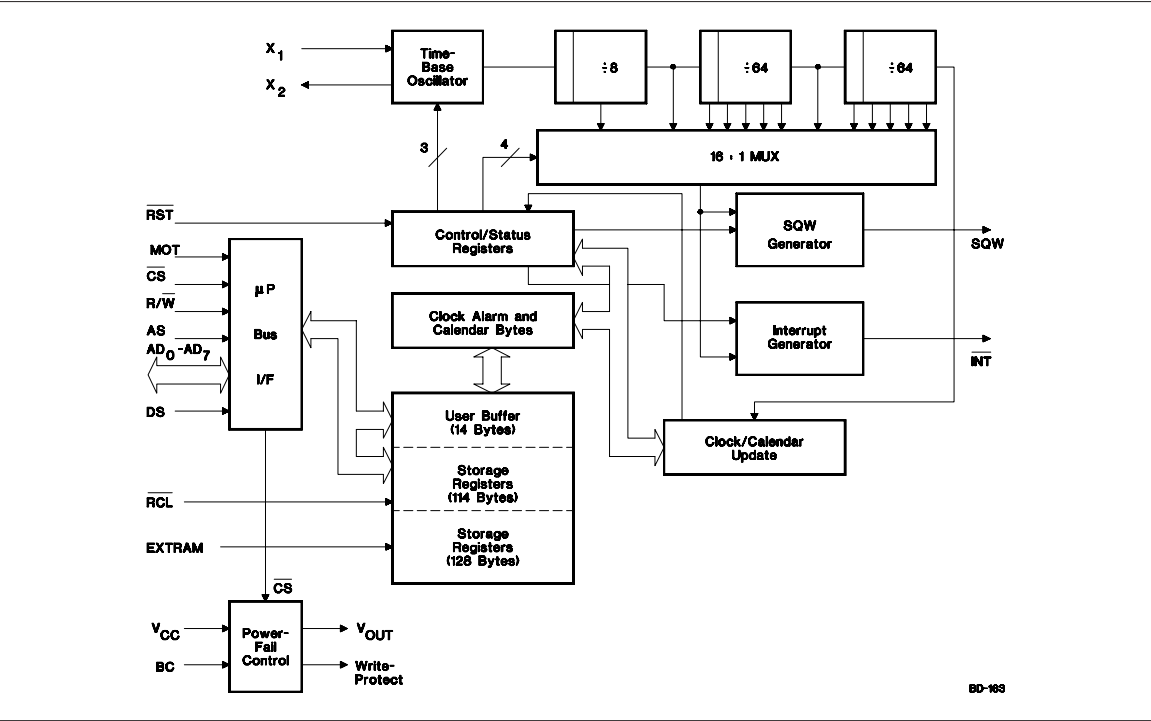


### Pin Names

|                                  |                                       |                         |                      |
|----------------------------------|---------------------------------------|-------------------------|----------------------|
| AD <sub>0</sub> –AD <sub>7</sub> | Multiplexed address/data input/output | $\overline{\text{RST}}$ | Reset input          |
| MOT                              | Bus type select input                 | SQW                     | Square wave output   |
| $\overline{\text{CS}}$           | Chip select input                     | EXTRAM                  | Extended RAM enable  |
| AS                               | Address strobe input                  | $\overline{\text{RCL}}$ | RAM clear input      |
| DS                               | Data strobe input                     | BC                      | 3V backup cell input |
| $\text{R}/\overline{\text{W}}$   | Read/write input                      | X1–X2                   | Crystal inputs       |
| $\overline{\text{INT}}$          | Interrupt request output              | V <sub>CC</sub>         | Power supply         |
|                                  |                                       | V <sub>SS</sub>         | Ground               |

bq3285E/L

Block Diagram



Pin Descriptions

**MOT**      **Bus type select input**

MOT selects bus timing for either Motorola or Intel architecture. This pin should be tied to V<sub>CC</sub> for Motorola timing or to V<sub>SS</sub> for Intel timing (see Table 1). The setting should not be changed during system operation. MOT is internally pulled low by a 30KΩ resistor.

Table 1. Bus Setup

| Bus Type | MOT Level       | DS Equivalent     | R/W Equivalent    | AS Equivalent |
|----------|-----------------|-------------------|-------------------|---------------|
| Motorola | V <sub>CC</sub> | DS, E, or Φ2      | R/W               | AS            |
| Intel    | V <sub>SS</sub> | RD, MEMR, or I/OR | WR, MEMW, or I/OW | ALE           |

AD<sub>0</sub>–AD<sub>7</sub>      **Multiplexed address/data input/output**

The bq3285E/L bus cycle consists of two phases: the address phase and the data-transfer phase. The address phase precedes the data-transfer phase. During the address phase, an address placed on AD<sub>0</sub>–AD<sub>7</sub> and EXTRAM is latched into the bq3285E/L on the falling edge of the AS signal. During the data-transfer phase of the bus cycle, the AD<sub>0</sub>–AD<sub>7</sub> pins serve as a bidirectional data bus.

AS      **Address strobe input**

AS serves to demultiplex the address/data bus. The falling edge of AS latches the address on AD<sub>0</sub>–AD<sub>7</sub> and EXTRAM. This demultiplexing process is independent of the CS signal. For DIP and SOIC packages with MOT = V<sub>SS</sub>, the AS input is provided a signal similar to ALE in an Intel-based system.

|                                    |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |                                    |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
|------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>DS</b>                          | <b>Data strobe input</b><br><br>When MOT = V <sub>CC</sub> , DS controls data transfer during a bq3285E/L bus cycle. During a read cycle, the bq3285E/L drives the bus after the rising edge on DS. During a write cycle, the falling edge on DS is used to latch write data into the chip.<br><br>When MOT = V <sub>SS</sub> , the DS input is provided a signal similar to $\overline{RD}$ , $\overline{MEMR}$ , or $\overline{I/OR}$ in an Intel-based system. The falling edge on DS is used to enable the outputs during a read cycle. | <b>EXTRAM</b>                      | <b>Extended RAM enable</b><br><br>Enables 128 bytes of additional nonvolatile SRAM. It is connected internally to a 30K $\Omega$ pull-down resistor. To access the RTC registers, EXTRAM must be low.                                                                                                                                                                                                                                                                                                                                                                                     |
| <b>R/W</b>                         | <b>Read/write input</b><br><br>When MOT = V <sub>CC</sub> , the level on $\overline{R/W}$ identifies the direction of data transfer. A high level on $\overline{R/W}$ indicates a read bus cycle, whereas a low on this pin indicates a write bus cycle.<br><br>When MOT = V <sub>SS</sub> , $\overline{R/W}$ is provided a signal similar to $\overline{WR}$ , $\overline{MEMW}$ , or $\overline{I/OW}$ in an Intel-based system. The rising edge on $\overline{R/W}$ latches data into the bq3285E/L.                                     | <b>RCL</b>                         | <b>RAM clear input</b><br><br>A low level on the $\overline{RCL}$ pin causes the contents of each of the 242 storage bytes to be set to FF(hex). The contents of the clock and control registers are unaffected. This pin should be used as a user-interface input (pushbutton to ground) and not connected to the output of any active component. $\overline{RCL}$ input is only recognized when held low for at least 125ms in the presence of V <sub>CC</sub> . Using RAM clear does not affect the battery load. This pin is connected internally to a 30K $\Omega$ pull-up resistor. |
| <b><math>\overline{CS}</math></b>  | <b>Chip select input</b><br><br>$\overline{CS}$ should be driven low and held stable during the data-transfer phase of a bus cycle accessing the bq3285E/L.                                                                                                                                                                                                                                                                                                                                                                                 | <b>BC</b>                          | <b>3V backup cell input</b><br><br>BC should be connected to a 3V backup cell for RTC operation and storage register non-volatility in the absence of system power. When V <sub>CC</sub> slews down past V <sub>BC</sub> (3V typical), the integral control circuitry switches the power source to BC. When V <sub>CC</sub> returns above V <sub>BC</sub> , the power source is switched to V <sub>CC</sub> .<br><br>Upon power-up, a voltage within the V <sub>BC</sub> range must be present on the BC pin for the oscillator to start up.                                              |
| <b><math>\overline{INT}</math></b> | <b>Interrupt request output</b><br><br>$\overline{INT}$ is an open-drain output. This allows alarm INT to be valid in battery-backup mode. To use this feature, $\overline{INT}$ must be connected to a power supply other than V <sub>CC</sub> . $\overline{INT}$ is asserted low when any event flag is set and the corresponding event enable bit is also set. $\overline{INT}$ becomes high-impedance whenever register C is read (see the Control/Status Registers section).                                                           | <b><math>\overline{RST}</math></b> | <b>Reset input</b><br><br>The bq3285E/L is reset when $\overline{RST}$ is pulled low. When reset, $\overline{INT}$ becomes high impedance, and the bq3285E/L is not accessible. Table 4 in the Control/Status Registers section lists the register bits that are cleared by a reset.<br><br>Reset may be disabled by connecting $\overline{RST}$ to V <sub>CC</sub> . This allows the control bits to retain their states through power-down/power-up cycles.                                                                                                                             |
| <b>SQW</b>                         | <b>Square-wave output</b><br><br>SQW may output a programmable frequency square-wave signal during normal (V <sub>CC</sub> valid) system operation. Any one of the 13 specific frequencies may be selected through register A. This pin is held low when the square-wave enable bit (SQWE) in register B is 0 (see the Control/Status Registers section).<br><br>A 32.768kHz output is enabled by setting the SQWE bit in register B to 1 and the 32KE bit in register C to 1 after setting OSC2–OSC0 in register A to 011 (binary).        | <b>X1–X2</b>                       | <b>Crystal inputs</b><br><br>The X1–X2 inputs are provided for an external 32.768kHz quartz crystal, Daiwa DT-26 or equivalent, with 6pF load capacitance. A trimming capacitor may be necessary for extremely precise time-base generation.<br><br>In the absence of a crystal, a 32.768kHz waveform can be fed into the X1 input.                                                                                                                                                                                                                                                       |

bq3285E/L

Functional Description

Address Map

The bq3285E/L provides 14 bytes of clock and control/status registers and 242 bytes of general nonvolatile storage. Figure 1 illustrates the address map for the bq3285E/L.

Update Period

The update period for the bq3285E/L is one second. The bq3285E/L updates the contents of the clock and calen-

dar locations during the update cycle at the end of each update period (see Figure 2). The alarm flag bit may also be set during the update cycle.

The bq3285E/L copies the local register updates into the user buffer accessed by the host processor. When a 1 is written to the update transfer inhibit bit (UTI) in register B, the user copy of the clock and calendar bytes remains unchanged, while the local copy of the same bytes continues to be updated every second.

The update-in-progress bit (UIP) in register A is set t<sub>BUC</sub> time before the beginning of an update cycle (see Figure 2). This bit is cleared and the update-complete flag (UF) is set at the end of the update cycle.

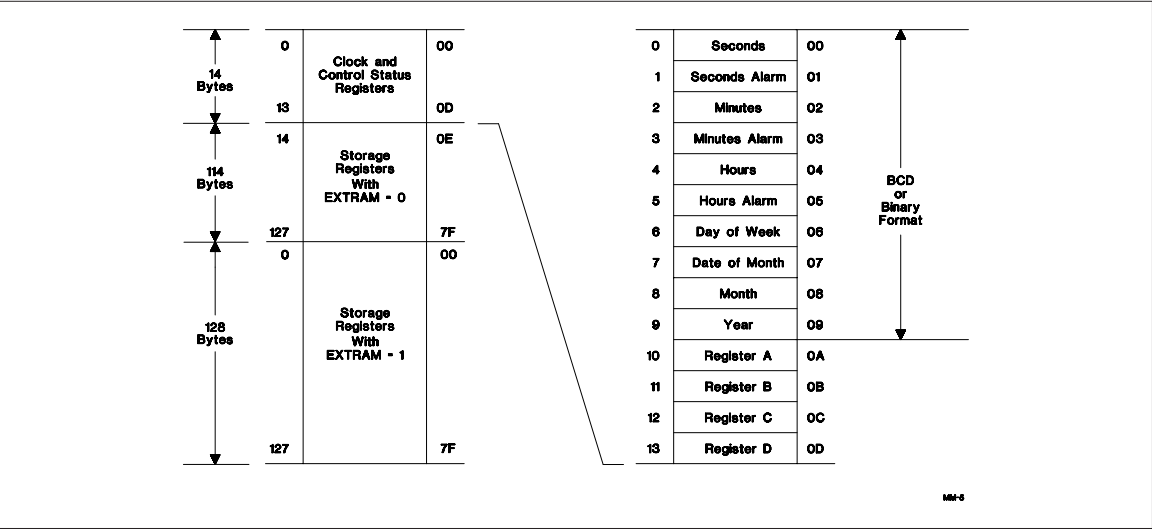


Figure 1. Address Map

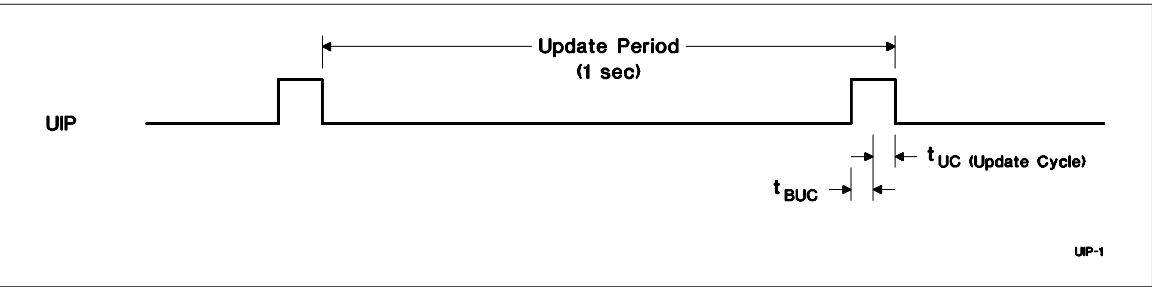


Figure 2. Update Period Timing and UIP

## Programming the RTC

The time-of-day, alarm, and calendar bytes can be written in either the BCD or binary format (see Table 2).

These steps may be followed to program the time, alarm, and calendar:

1. Modify the contents of register B:
  - a. Write a 1 to the UTI bit to prevent transfers between RTC bytes and user buffer.
  - b. Write the appropriate value to the data format (DF) bit to select BCD or binary format for all time, alarm, and calendar bytes.
2. Write new values to all the time, alarm, and calendar locations.
3. Clear the UTI bit to allow update transfers.

c. Write the appropriate value to the hour format (HF) bit.

On the next update cycle, the RTC updates all 10 bytes in the selected format.

**Table 2. Time, Alarm, and Calendar Formats**

| Address | RTC Bytes                   | Range   |                           |                           |
|---------|-----------------------------|---------|---------------------------|---------------------------|
|         |                             | Decimal | Binary                    | Binary-Coded Decimal      |
| 0       | Seconds                     | 0–59    | 00H–3BH                   | 00H–59H                   |
| 1       | Seconds alarm               | 0–59    | 00H–3BH                   | 00H–59H                   |
| 2       | Minutes                     | 0–59    | 00H–3BH                   | 00H–59H                   |
| 3       | Minutes alarm               | 0–59    | 00H–3BH                   | 00H–59H                   |
| 4       | Hours, 12-hour format       | 1–12    | 01H–0CH AM;<br>81H–8CH PM | 01H–12H AM;<br>81H–92H PM |
|         | Hours, 24-hour format       | 0–23    | 00H–17H                   | 00H–23H                   |
| 5       | Hours alarm, 12-hour format | 1–12    | 01H–0CH AM;<br>81H–8CH PM | 01H–12H AM;<br>81H–92H PM |
|         | Hours alarm, 24-hour format | 0–23    | 00H–17H                   | 00H–23H                   |
| 6       | Day of week (1=Sunday)      | 1–7     | 01H–07H                   | 01H–07H                   |
| 7       | Day of month                | 1–31    | 01H–1FH                   | 01H–31H                   |
| 8       | Month                       | 1–12    | 01H–0CH                   | 01H–12H                   |
| 9       | Year                        | 0–99    | 00H–63H                   | 00H–99H                   |

## bq3285E/L

### Square-Wave Output

The bq3285E/L divides the 32.768kHz oscillator frequency to produce the 1Hz update frequency for the clock and calendar. Thirteen taps from the frequency divider are fed to a 16:1 multiplexer circuit. The output of this mux is fed to the SQW output and periodic interrupt generation circuitry. The four least-significant bits of register A, RS0–RS3, select among the 13 taps (see Table 3). The square-wave output is enabled by writing a 1 to the square-wave enable bit (SQWE) in register B. A 32.768kHz output may be selected by setting OSC2–OSC0 in register A to 011 while SQWE = 1 and 32KE = 1.

### Interrupts

The bq3285E/L allows three individually selected interrupt events to generate an interrupt request. These three interrupt events are:

- The periodic interrupt, programmable to occur once every 122 $\mu$ s to 500ms.

- The alarm interrupt, programmable to occur once per second to once per day, is active in battery-backup mode, providing a “wake-up” feature.
- The update-ended interrupt, which occurs at the end of each update cycle.

Each of the three interrupt events is enabled by an individual interrupt-enable bit in register B. When an event occurs, its event flag bit in register C is set. If the corresponding event enable bit is also set, then an interrupt request is generated. The interrupt request flag bit (INTF) of register C is set with every interrupt request. Reading register C clears all flag bits, including INTF, and makes INT high-impedance.

Two methods can be used to process bq3285E/L interrupt events:

- Enable interrupt events and use the interrupt request output to invoke an interrupt service routine.
- Do not enable the interrupts and use a polling routine to periodically check the status of the flag bits.

The individual interrupt sources are described in detail in the following sections.

**Table 3. Square-Wave Frequency/Periodic Interrupt Rate**

| Register A Bits |      |      |     |     |     |     | Square Wave |       | Periodic Interrupt               |         |
|-----------------|------|------|-----|-----|-----|-----|-------------|-------|----------------------------------|---------|
| OSC2            | OSC1 | OSC0 | RS3 | RS2 | RS1 | RS0 | Frequency   | Units | Period                           | Units   |
| 0               | 1    | 0    | 0   | 0   | 0   | 0   | None        |       | None                             |         |
| 0               | 1    | 0    | 0   | 0   | 0   | 1   | 256         | Hz    | 3.90625                          | ms      |
| 0               | 1    | 0    | 0   | 0   | 1   | 0   | 128         | Hz    | 7.8125                           | ms      |
| 0               | 1    | 0    | 0   | 0   | 1   | 1   | 8.192       | kHz   | 122.070                          | $\mu$ s |
| 0               | 1    | 0    | 0   | 1   | 0   | 0   | 4.096       | kHz   | 244.141                          | $\mu$ s |
| 0               | 1    | 0    | 0   | 1   | 0   | 1   | 2.048       | kHz   | 488.281                          | $\mu$ s |
| 0               | 1    | 0    | 0   | 1   | 1   | 0   | 1.024       | kHz   | 976.5625                         | $\mu$ s |
| 0               | 1    | 0    | 0   | 1   | 1   | 1   | 512         | Hz    | 1.95315                          | ms      |
| 0               | 1    | 0    | 1   | 0   | 0   | 0   | 256         | Hz    | 3.90625                          | ms      |
| 0               | 1    | 0    | 1   | 0   | 0   | 1   | 128         | Hz    | 7.8125                           | ms      |
| 0               | 1    | 0    | 1   | 0   | 1   | 0   | 64          | Hz    | 15.625                           | ms      |
| 0               | 1    | 0    | 1   | 0   | 1   | 1   | 32          | Hz    | 31.25                            | ms      |
| 0               | 1    | 0    | 1   | 1   | 0   | 0   | 16          | Hz    | 62.5                             | ms      |
| 0               | 1    | 0    | 1   | 1   | 0   | 1   | 8           | Hz    | 125                              | ms      |
| 0               | 1    | 0    | 1   | 1   | 1   | 0   | 4           | Hz    | 250                              | ms      |
| 0               | 1    | 0    | 1   | 1   | 1   | 1   | 2           | Hz    | 500                              | ms      |
| 0               | 1    | 1    | X   | X   | X   | X   | 32.768      | kHz   | same as above defined by RS3–RS0 |         |

## Periodic Interrupt

The mux output used to drive the SQW output also drives the interrupt-generation circuitry. If the periodic interrupt event is enabled by writing a 1 to the periodic interrupt enable bit (PIE) in register C, an interrupt request is generated once every 122 $\mu$ s to 500ms. The period between interrupts is selected by the same bits in register A that select the square wave frequency (see Table 3). Setting OSC2–OSC0 in register A to 011 does not affect the periodic interrupt timing.

## Alarm Interrupt

The alarm interrupt is active in battery-backup mode, providing a “wake-up” capability. During each update cycle, the RTC compares the hours, minutes, and seconds bytes with the three corresponding alarm bytes. If a match of all bytes is found, the alarm interrupt event flag bit, AF in register C, is set to 1. If the alarm event is enabled, an interrupt request is generated.

An alarm byte may be removed from the comparison by setting it to a “don’t care” state. An alarm byte is set to a “don’t care” state by writing a 1 to each of its two most-significant bits. A “don’t care” state may be used to select the frequency of alarm interrupt events as follows:

- If none of the three alarm bytes is “don’t care,” the frequency is once per day, when hours, minutes, and seconds match.
- If only the hour alarm byte is “don’t care,” the frequency is once per hour, when minutes and seconds match.
- If only the hour and minute alarm bytes are “don’t care,” the frequency is once per minute, when seconds match.
- If the hour, minute, and second alarm bytes are “don’t care,” the frequency is once per second.

## Update Cycle Interrupt

The update cycle ended flag bit (UF) in register C is set to a 1 at the end of an update cycle. If the update interrupt enable bit (UIE) of register B is 1, and the update transfer inhibit bit (UTI) in register B is 0, then an interrupt request is generated at the end of each update cycle.

## Accessing RTC bytes

The EXTRAM pin must be low to access the RTC registers. Time and calendar bytes read during an update cycle may be in error. Three methods to access the time and calendar bytes without ambiguity are:

- Enable the update interrupt event to generate interrupt requests at the end of the update cycle. The interrupt handler has a maximum of 999ms to access the clock bytes before the next update cycle begins (see Figure 3).
- Poll the update-in-progress bit (UIP) in register A. If  $UIP = 0$ , the polling routine has a minimum of  $t_{BUC}$  time to access the clock bytes (see Figure 3).
- Use the periodic interrupt event to generate interrupt requests every  $t_{PI}$  time, such that  $UIP = 1$  always occurs between the periodic interrupts. The interrupt handler has a minimum of  $t_{PI}/2 + t_{BUC}$  time to access the clock bytes (see Figure 3).

## Oscillator Control

When power is first applied to the bq3285E/L and  $V_{CC}$  is above  $V_{PFD}$ , the internal oscillator and frequency divider are turned on by writing a 010 pattern to bits 4 through 6 of register A. A pattern of 011 behaves as 010 but additionally transforms register C into a read/write register. This allows the 32.768kHz output on the square wave pin to be turned on. A pattern of 11X turns the oscillator on, but keeps the frequency divider disabled. Any other pattern to these bits keeps the oscillator off.

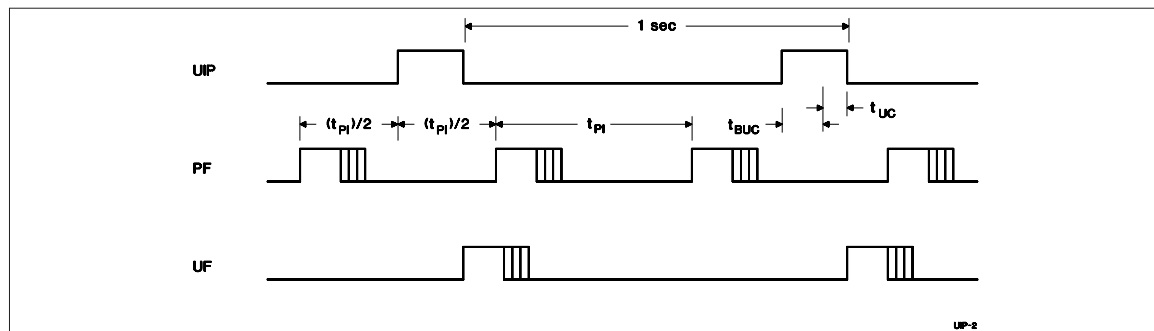


Figure 3. Update-Ended/Periodic Interrupt Relationship

## bq3285E/L

### Power-Down/Power-Up Cycle

The bq3285E and bq3285L power-up/power-down cycles are different. The bq3285L continuously monitors  $V_{CC}$  for out-of-tolerance. During a power failure, when  $V_{CC}$  falls below  $V_{PFD}$  (2.53V typical), the bq3285L write-protects the clock and storage registers. The power source is switched to BC when  $V_{CC}$  is less than  $V_{PFD}$  and BC is greater than  $V_{PFD}$ , or when  $V_{CC}$  is less than  $V_{BC}$  and  $V_{BC}$  is less than  $V_{PFD}$ . RTC operation and storage data are sustained by a valid backup energy source. When  $V_{CC}$  is above  $V_{PFD}$ , the power source is  $V_{CC}$ . Write-protection continues for  $t_{CSR}$  time after  $V_{CC}$  rises above  $V_{PFD}$ .

The bq3285E continuously monitors  $V_{CC}$  for out-of-tolerance. During a power failure, when  $V_{CC}$  falls below  $V_{PFD}$  (4.17V typical), the bq3285E write-protects the clock and storage registers. When  $V_{CC}$  is below  $V_{BC}$  (3V typical), the power source is switched to BC. RTC operation and storage data are sustained by a valid backup energy source. When  $V_{CC}$  is above  $V_{BC}$ , the power source is  $V_{CC}$ . Write-protection continues for  $t_{CSR}$  time after  $V_{CC}$  rises above  $V_{PFD}$ .

### Control/Status Registers

The four control/status registers of the bq3285E/L are accessible regardless of the status of the update cycle (see Table 4).

#### Register A

| Register A Bits |     |     |     |     |     |     |     |
|-----------------|-----|-----|-----|-----|-----|-----|-----|
| 7               | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
| UIP             | OS2 | OS1 | OS0 | RS3 | RS2 | RS1 | RS0 |

Register A programs:

- The frequency of the square-wave and the periodic event rate.
- Oscillator operation.

Register A provides:

- Status of the update cycle.

#### RS0–RS3 - Frequency Select

| 7 | 6 | 5 | 4 | 3   | 2   | 1   | 0   |
|---|---|---|---|-----|-----|-----|-----|
| - | - | - | - | RS3 | RS2 | RS1 | RS0 |

These bits select one of the 13 frequencies for the SQW output and the periodic interrupt rate, as shown in Table 3.

#### OS0–OS2 - Oscillator Control

| 7 | 6   | 5   | 4   | 3 | 2 | 1 | 0 |
|---|-----|-----|-----|---|---|---|---|
| - | OS2 | OS1 | OS0 | - | - | - | - |

These three bits control the state of the oscillator and divider stages. A pattern of 010 enables RTC operation by turning on the oscillator and enabling the frequency divider. A pattern of 011 behaves as 010 but additionally transforms register C into a read/write register. This allows the 32.768kHz output on the square wave pin to be turned on. A pattern of 11X turns the oscillator on, but keeps the frequency divider disabled. When 010 is written, the RTC begins its first update after 500ms.

#### UIP - Update Cycle Status

| 7   | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|---|---|---|---|---|---|---|
| UIP | - | - | - | - | - | - | - |

This read-only bit is set prior to the update cycle. When UIP equals 1, an RTC update cycle may be in progress. UIP is cleared at the end of each update cycle. This bit is also cleared when the update transfer inhibit (UTI) bit in register B is 1.

**Table 4. Control/Status Registers**

| Reg. | Loc. (Hex) | Read | Write            | Bit Name and State on Reset |    |     |    |     |    |     |         |      |    |      |    |     |    |     |    |
|------|------------|------|------------------|-----------------------------|----|-----|----|-----|----|-----|---------|------|----|------|----|-----|----|-----|----|
|      |            |      |                  | 7 (MSB)                     | 6  | 5   | 4  | 3   | 2  | 1   | 0 (LSB) |      |    |      |    |     |    |     |    |
| A    | 0A         | Yes  | Yes <sup>1</sup> | UIP                         | na | OS2 | na | OS1 | na | OS0 | na      | RS3  | na | RS2  | na | RS1 | na | RS0 | na |
| B    | 0B         | Yes  | Yes              | UTI                         | na | PIE | 0  | AIE | 0  | UIE | 0       | SQWE | 0  | DF   | na | HF  | na | DSE | na |
| C    | 0C         | Yes  | No <sup>2</sup>  | INTF                        | 0  | PF  | 0  | AF  | 0  | UF  | 0       | -    | 0  | 32KE | na | -   | 0  | -   | 0  |
| D    | 0D         | Yes  | No               | VRT                         | na | -   | 0  | -   | 0  | -   | 0       | -    | 0  | -    | 0  | -   | 0  | -   | 0  |

#### Notes:

na = not affected.

1. Except bit 7.

2. Read/write only when OSC2–OSC0 in register A is 011 (binary).

**Register B**

| Register B Bits |     |     |     |      |    |    |     |
|-----------------|-----|-----|-----|------|----|----|-----|
| 7               | 6   | 5   | 4   | 3    | 2  | 1  | 0   |
| UTI             | PIE | AIE | UIE | SQWE | DF | HF | DSE |

Register B enables:

- Update cycle transfer operation
- Square-wave output
- Interrupt events
- Daylight saving adjustment

Register B selects:

- Clock and calendar data formats

All bits of register B are read/write.

**DSE - Daylight Saving Enable**

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0   |
|---|---|---|---|---|---|---|-----|
| - | - | - | - | - | - | - | DSE |

This bit enables daylight-saving time adjustments when written to 1:

- On the last Sunday in October, the first time the bq3285E/L increments past 1:59:59 AM, the time falls back to 1:00:00 AM.
- On the first Sunday in April, the time springs forward from 2:00:00 AM to 3:00:00 AM.

**HF - Hour Format**

| 7 | 6 | 5 | 4 | 3 | 2 | 1  | 0 |
|---|---|---|---|---|---|----|---|
| - | - | - | - | - | - | HF | - |

This bit selects the time-of-day and alarm hour format:

- 1 = 24-hour format
- 0 = 12-hour format

**DF - Data Format**

| 7 | 6 | 5 | 4 | 3 | 2  | 1 | 0 |
|---|---|---|---|---|----|---|---|
| - | - | - | - | - | DF | - | - |

This bit selects the numeric format in which the time, alarm, and calendar bytes are represented:

- 1 = Binary
- 0 = BCD

**SQWE - Square-Wave Enable**

| 7 | 6 | 5 | 4 | 3    | 2 | 1 | 0 |
|---|---|---|---|------|---|---|---|
| - | - | - | - | SQWE | - | - | - |

This bit enables the square-wave output:

- 1 = Enabled
- 0 = Disabled and held low

**UIE - Update Cycle Interrupt Enable**

| 7 | 6 | 5 | 4   | 3 | 2 | 1 | 0 |
|---|---|---|-----|---|---|---|---|
| - | - | - | UIE | - | - | - | - |

This bit enables an interrupt request due to an update ended interrupt event:

- 1 = Enabled
- 0 = Disabled

The UIE bit is automatically cleared when the UTI bit equals 1.

**AIE - Alarm Interrupt Enable**

| 7 | 6 | 5   | 4 | 3 | 2 | 1 | 0 |
|---|---|-----|---|---|---|---|---|
| - | - | AIE | - | - | - | - | - |

This bit enables an interrupt request due to an alarm interrupt event:

- 1 = Enabled
- 0 = Disabled

**PIE - Periodic Interrupt Enable**

| 7 | 6   | 5 | 4 | 3 | 2 | 1 | 0 |
|---|-----|---|---|---|---|---|---|
| - | PIE | - | - | - | - | - | - |

This bit enables an interrupt request due to a periodic interrupt event:

- 1 = Enabled
- 0 = Disabled

## bq3285E/L

### UTI - Update Transfer Inhibit

| 7   | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|---|---|---|---|---|---|---|
| UTI | - | - | - | - | - | - | - |

This bit inhibits the transfer of RTC bytes to the user buffer:

1 = Inhibits transfer and clears UIE

0 = Allows transfer

### Register C

Register C is the read-only event status register.

| Register C Bits |    |    |    |   |      |   |   |
|-----------------|----|----|----|---|------|---|---|
| 7               | 6  | 5  | 4  | 3 | 2    | 1 | 0 |
| INTF            | PF | AF | UF | 0 | 32KE | 0 | 0 |

### Bits 0, 1, 3 - Unused Bits

These bits are always set to 0.

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| - | - | - | - | 0 | - | 0 | 0 |

### 32KE - 32kHz Enable Output

This bit may be set to a 1 only when the OSC2-OSC0 bits in register A are set to 011. Setting OSC2-OSC0 to

| 7 | 6 | 5 | 4 | 3 | 2    | 1 | 0 |
|---|---|---|---|---|------|---|---|
| - | - | - | - | - | 32KE | - | - |

anything other than 011 clears this bit. If SQWE in register B and 32KE are set, a 32.768kHz waveform is output on the square wave pin.

### UF - Update Event Flag

This bit is set to a 1 at the end of the update cycle.

| 7 | 6 | 5 | 4  | 3 | 2 | 1 | 0 |
|---|---|---|----|---|---|---|---|
| - | - | - | UF | - | - | - | - |

Reading register C clears this bit.

### AF - Alarm Event Flag

This bit is set to a 1 when an alarm event occurs. Reading register C clears this bit.

| 7 | 6 | 5  | 4 | 3 | 2 | 1 | 0 |
|---|---|----|---|---|---|---|---|
| - | - | AF | - | - | - | - | - |

### PF - Periodic Event Flag

This bit is set to a 1 every  $t_{PI}$  time, where  $t_{PI}$  is the time period selected by the settings of RS0-RS3 in register A. Reading register C clears this bit.

| 7 | 6  | 5 | 4 | 3 | 2 | 1 | 0 |
|---|----|---|---|---|---|---|---|
| - | PF | - | - | - | - | - | - |

### INTF - Interrupt Request Flag

This flag is set to a 1 when any of the following is true:

AIE = 1 and AF = 1

PIE = 1 and PF = 1

| 7    | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|------|---|---|---|---|---|---|---|
| INTF | - | - | - | - | - | - | - |

UIE = 1 and UF = 1

Reading register C clears this bit.

### Register D

Register D is the read-only data integrity status register.

### Bits 0-6 - Unused Bits

These bits are always set to 0.

### VRT - Valid RAM and Time

| Register D Bits |   |   |   |   |   |   |   |
|-----------------|---|---|---|---|---|---|---|
| 7               | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
| VRT             | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

1 = Valid backup energy source

0 = Backup energy source is depleted

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---|---|---|---|---|---|---|---|
| - | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

When the backup energy source is depleted (VRT = 0), data integrity of the RTC and storage registers is not guaranteed.

| 7   | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-----|---|---|---|---|---|---|---|
| VRT | - | - | - | - | - | - | - |

**Absolute Maximum Ratings—bq3285E**

| Symbol              | Parameter                                                                           | Value       | Unit | Conditions                             |
|---------------------|-------------------------------------------------------------------------------------|-------------|------|----------------------------------------|
| V <sub>CC</sub>     | DC voltage applied on V <sub>CC</sub> relative to V <sub>SS</sub>                   | -0.3 to 7.0 | V    |                                        |
| V <sub>T</sub>      | DC voltage applied on any pin excluding V <sub>CC</sub> relative to V <sub>SS</sub> | -0.3 to 7.0 | V    | V <sub>T</sub> ≤ V <sub>CC</sub> + 0.3 |
| T <sub>OPR</sub>    | Operating temperature                                                               | 0 to +70    | °C   | Commercial                             |
|                     |                                                                                     |             |      |                                        |
| T <sub>STG</sub>    | Storage temperature                                                                 | -55 to +125 | °C   |                                        |
| T <sub>BIAS</sub>   | Temperature under bias                                                              | -40 to +85  | °C   |                                        |
| T <sub>SOLDER</sub> | Soldering temperature                                                               | 260         | °C   | For 10 seconds                         |

**Note:** Permanent device damage may occur if **Absolute Maximum Ratings** are exceeded. Functional operation should be limited to the Recommended DC Operating Conditions detailed in this data sheet. Exposure to conditions beyond the operational limits for extended periods of time may affect device reliability.

**Absolute Maximum Ratings—bq3285L**

| Symbol              | Parameter                                                                           | Value       | Unit | Conditions                             |
|---------------------|-------------------------------------------------------------------------------------|-------------|------|----------------------------------------|
| V <sub>CC</sub>     | DC voltage applied on V <sub>CC</sub> relative to V <sub>SS</sub>                   | -0.3 to 6.0 | V    |                                        |
| V <sub>T</sub>      | DC voltage applied on any pin excluding V <sub>CC</sub> relative to V <sub>SS</sub> | -0.3 to 6.0 | V    | V <sub>T</sub> ≤ V <sub>CC</sub> + 0.3 |
| T <sub>OPR</sub>    | Operating temperature                                                               | 0 to +70    | °C   | Commercial                             |
| T <sub>STG</sub>    | Storage temperature                                                                 | -55 to +125 | °C   |                                        |
| T <sub>BIAS</sub>   | Temperature under bias                                                              | -40 to +85  | °C   |                                        |
| T <sub>SOLDER</sub> | Soldering temperature                                                               | 260         | °C   | For 10 seconds                         |

**Note:** Permanent device damage may occur if **Absolute Maximum Ratings** are exceeded. Functional operation should be limited to the Recommended DC Operating Conditions detailed in this data sheet. Exposure to conditions beyond the operational limits for extended periods of time may affect device reliability.

## bq3285E/L

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### Recommended DC Operating Conditions—bq3285E ( $T_A = T_{OPR}$ )

| Symbol          | Parameter           | Minimum | Typical | Maximum               | Unit |
|-----------------|---------------------|---------|---------|-----------------------|------|
| V <sub>CC</sub> | Supply voltage      | 4.5     | 5.0     | 5.5                   | V    |
| V <sub>SS</sub> | Supply voltage      | 0       | 0       | 0                     | V    |
| V <sub>IL</sub> | Input low voltage   | -0.3    | -       | 0.8                   | V    |
| V <sub>IH</sub> | Input high voltage  | 2.2     | -       | V <sub>CC</sub> + 0.3 | V    |
| V <sub>BC</sub> | Backup cell voltage | 2.5     | -       | 4.0                   | V    |

**Note:** Typical values indicate operation at  $T_A = 25^\circ\text{C}$ .

### Recommended DC Operating Conditions—bq3285L ( $T_A = T_{OPR}$ )

| Symbol          | Parameter           | Minimum | Typical | Maximum               | Unit |
|-----------------|---------------------|---------|---------|-----------------------|------|
| V <sub>CC</sub> | Supply voltage      | 2.7     | 3.15    | 3.6                   | V    |
| V <sub>SS</sub> | Supply voltage      | 0       | 0       | 0                     | V    |
| V <sub>IL</sub> | Input low voltage   | -0.3    | -       | 0.6                   | V    |
| V <sub>IH</sub> | Input high voltage  | 2.2     | -       | V <sub>CC</sub> + 0.3 | V    |
| V <sub>BC</sub> | Backup cell voltage | 2.4     | -       | 4.0                   | V    |

**Note:** Typical values indicate operation at  $T_A = 25^\circ\text{C}$ .

### Crystal Specifications—bq3285E/L (DT-26 or Equivalent)

| Symbol                         | Parameter                    | Minimum | Typical | Maximum | Unit   |
|--------------------------------|------------------------------|---------|---------|---------|--------|
| f <sub>0</sub>                 | Oscillation frequency        | -       | 32.768  | -       | kHz    |
| C <sub>L</sub>                 | Load capacitance             | -       | 6       | -       | pF     |
| T <sub>P</sub>                 | Temperature turnover point   | 20      | 25      | 30      | °C     |
| k                              | Parabolic curvature constant | -       | -       | -0.042  | ppm/°C |
| Q                              | Quality factor               | 40,000  | 70,000  | -       |        |
| R <sub>1</sub>                 | Series resistance            | -       | -       | 45      | KΩ     |
| C <sub>0</sub>                 | Shunt capacitance            | -       | 1.1     | 1.8     | pF     |
| C <sub>0</sub> /C <sub>1</sub> | Capacitance ratio            | -       | 430     | 600     |        |
| D <sub>L</sub>                 | Drive level                  | -       | -       | 1       | μW     |
| Δf/f <sub>0</sub>              | Aging (first year at 25°C)   | -       | 1       | -       | ppm    |

**DC Electrical Characteristics—bq3285E** ( $T_A = T_{OPR}$ ,  $V_{CC} = 5V \pm 10\%$ )

| Symbol      | Parameter                                      | Minimum | Typical  | Maximum | Unit    | Conditions/Notes                                                                               |
|-------------|------------------------------------------------|---------|----------|---------|---------|------------------------------------------------------------------------------------------------|
| $I_{LI}$    | Input leakage current                          | -       | -        | $\pm 1$ | $\mu A$ | $V_{IN} = V_{SS}$ to $V_{CC}$                                                                  |
| $I_{LO}$    | Output leakage current                         | -       | -        | $\pm 1$ | $\mu A$ | $AD_0$ – $AD_7$ , $\overline{INT}$ , and SQW in high impedance, $V_{OUT} = V_{SS}$ to $V_{CC}$ |
| $V_{OH}$    | Output high voltage                            | 2.4     | -        | -       | V       | $I_{OH} = -2.0$ mA                                                                             |
| $V_{OL}$    | Output low voltage                             | -       | -        | 0.4     | V       | $I_{OL} = 4.0$ mA                                                                              |
| $I_{CC}$    | Operating supply current                       | -       | 7        | 15      | mA      | Min. cycle, duty = 100%, $I_{OH} = 0$ mA, $I_{OL} = 0$ mA                                      |
| $I_{CCSB}$  | Standby supply current                         | -       | 300      | -       | $\mu A$ | $V_{IN} = V_{SS}$ or $V_{CC}$ , $CS \geq V_{CC} - 0.2$                                         |
| $V_{SO}$    | Supply switch-over voltage                     | -       | $V_{BC}$ | -       | V       |                                                                                                |
| $I_{CCB}$   | Battery operation current                      | -       | 0.3      | 0.5     | $\mu A$ | $V_{BC} = 3V$ , $T_A = 25^\circ C$                                                             |
| $V_{PFD}$   | Power-fail-detect voltage                      | 4.0     | 4.17     | 4.35    | V       |                                                                                                |
| $I_{RCL}$   | Input current when $\overline{RCL} = V_{SS}$ . | -       | -        | 185     | $\mu A$ | Internal 30K pull-up                                                                           |
| $I_{MOTH}$  | Input current when $MOT = V_{CC}$              | -       | -        | -185    | $\mu A$ | Internal 30K pull-down                                                                         |
|             | Input current when $MOT = V_{SS}$              | -       | -        | 0       | $\mu A$ | Internal 30K pull-down                                                                         |
| $I_{XTRAM}$ | Input current when EXTRAM = $V_{CC}$           | -       | -        | -185    | $\mu A$ | Internal 30K pull-down                                                                         |
|             | Input current when EXTRAM = $V_{SS}$           | -       | -        | 0       | $\mu A$ | Internal 30K pull-down                                                                         |

**Note:** Typical values indicate operation at  $T_A = 25^\circ C$ ,  $V_{CC} = 5V$  or  $V_{BC} = 3V$ .

## bq3285E/L

### DC Electrical Characteristics—bq3285L ( $T_A = T_{OPR}$ , $V_{CC} = 3.15V \pm 0.45V$ )

| Symbol      | Parameter                                      | Minimum | Typical   | Maximum | Unit    | Conditions/Notes                                                                       |
|-------------|------------------------------------------------|---------|-----------|---------|---------|----------------------------------------------------------------------------------------|
| $I_{LI}$    | Input leakage current                          | -       | -         | $\pm 1$ | $\mu A$ | $V_{IN} = V_{SS}$ to $V_{CC}$                                                          |
| $I_{LO}$    | Output leakage current                         | -       | -         | $\pm 1$ | $\mu A$ | $AD_0$ – $AD_7$ and $\overline{INT}$ in high impedance, $V_{OUT} = V_{SS}$ to $V_{CC}$ |
| $V_{OH}$    | Output high voltage                            | 2.2     | -         | -       | V       | $I_{OH} = -1.0$ mA                                                                     |
| $V_{OL}$    | Output low voltage                             | -       | -         | 0.4     | V       | $I_{OL} = 2.0$ mA                                                                      |
| $I_{CC}$    | Operating supply current                       | -       | 5         | 9       | mA      | Min. cycle, duty = 100%, $I_{OH} = 0$ mA, $I_{OL} = 0$ mA                              |
| $I_{CCSB}$  | Standby supply current                         | -       | 100       | -       | $\mu A$ | $V_{IN} = V_{SS}$ or $V_{CC}$ , $CS \geq V_{CC} - 0.2$                                 |
| $V_{SO}$    | Supply switch-over voltage                     | -       | $V_{PFD}$ | -       | V       | $V_{BC} > V_{PFD}$                                                                     |
|             |                                                | -       | $V_{BC}$  | -       | V       | $V_{BC} < V_{PFD}$                                                                     |
| $I_{CCB}$   | Battery operation current                      | -       | 0.3       | 0.5     | $\mu A$ | $V_{BC} = 3V$ , $T_A = 25^\circ C$ , $V_{CC} < V_{BC}$                                 |
| $V_{PFD}$   | Power-fail-detect voltage                      | 2.4     | 2.53      | 2.65    | V       |                                                                                        |
| $I_{RCL}$   | Input current when $\overline{RCL} = V_{SS}$ . | -       | -         | 120     | $\mu A$ | Internal 30K pull-up                                                                   |
| $I_{MOTH}$  | Input current when $MOT = V_{CC}$              | -       | -         | -120    | $\mu A$ | Internal 30K pull-down                                                                 |
|             | Input current when $MOT = V_{SS}$              | -       | -         | 0       | $\mu A$ | Internal 30K pull-down                                                                 |
| $I_{XTRAM}$ | Input current when $EXTRAM = V_{CC}$           | -       | -         | -120    | $\mu A$ | Internal 30K pull-down                                                                 |
|             | Input current when $EXTRAM = V_{SS}$           | -       | -         | 0       | $\mu A$ | Internal 30K pull-down                                                                 |

**Note:** Typical values indicate operation at  $T_A = 25^\circ C$ ,  $V_{CC} = 3V$ .

**Capacitance—bq3285E/L** ( $T_A = 25^\circ\text{C}$ ,  $F = 1\text{MHz}$ ,  $V_{CC} = 5.0\text{V}$ )

| Symbol    | Parameter                | Minimum | Typical | Maximum | Unit | Conditions            |
|-----------|--------------------------|---------|---------|---------|------|-----------------------|
| $C_{I/O}$ | Input/output capacitance | -       | -       | 7       | pF   | $V_{OUT} = 0\text{V}$ |
| $C_{IN}$  | Input capacitance        | -       | -       | 5       | pF   | $V_{IN} = 0\text{V}$  |

**Note:** This parameter is sampled and not 100% tested. It does not include the X1 or X2 pin.

**AC Test Conditions—bq3285E**

| Parameter                                | Test Conditions                    |
|------------------------------------------|------------------------------------|
| Input pulse levels                       | 0 to 3.0 V                         |
| Input rise and fall times                | 5 ns                               |
| Input and output timing reference levels | 1.5 V (unless otherwise specified) |
| Output load (including scope and jig)    | See Figures 4 and 5                |

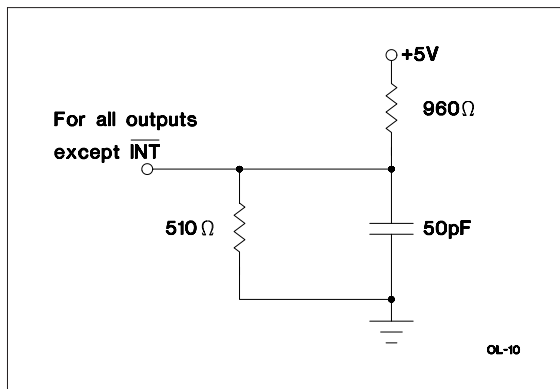


Figure 4. Output Load A—bq3285E

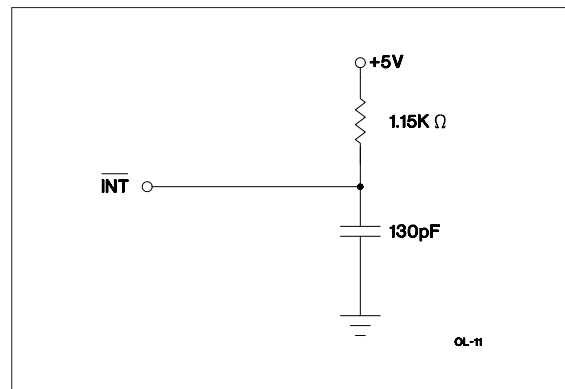


Figure 5. Output Load B—bq3285E

AC Test Conditions—bq3285L

| Parameter                                | Test Conditions                    |
|------------------------------------------|------------------------------------|
| Input pulse levels                       | 0 to 2.3 V                         |
| Input rise and fall times                | 5 ns                               |
| Input and output timing reference levels | 1.2 V (unless otherwise specified) |
| Output load (including scope and jig)    | See Figures 6 and 7                |

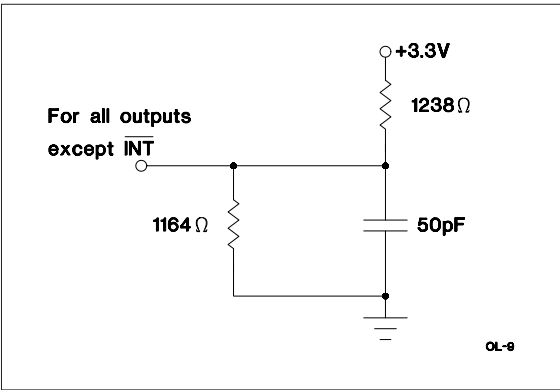


Figure 6. Output Load A—bq3285L

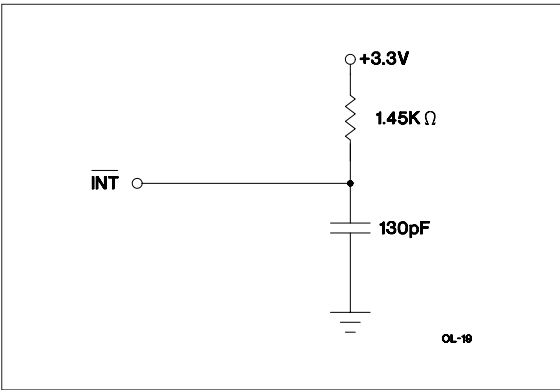


Figure 7. Output Load B—bq3285L

**Read/Write Timing—bq3285E** ( $T_A = T_{OPR}$ ,  $V_{CC} = 5V \pm 10\%$ )

| Symbol           | Parameter                                                       | Minimum | Typical | Maximum | Unit | Notes       |
|------------------|-----------------------------------------------------------------|---------|---------|---------|------|-------------|
| t <sub>CYC</sub> | Cycle time                                                      | 160     | -       | -       | ns   |             |
| t <sub>DSL</sub> | DS low or $\overline{RD}/\overline{WR}$ high time               | 80      | -       | -       | ns   |             |
| t <sub>DSH</sub> | DS high or $\overline{RD}/\overline{WR}$ low time               | 55      | -       | -       | ns   |             |
| t <sub>RWH</sub> | $R/\overline{W}$ hold time                                      | 0       | -       | -       | ns   |             |
| t <sub>RWS</sub> | $R/\overline{W}$ setup time                                     | 10      | -       | -       | ns   |             |
| t <sub>CS</sub>  | Chip select setup time                                          | 5       | -       | -       | ns   |             |
| t <sub>CH</sub>  | Chip select hold time                                           | 0       | -       | -       | ns   |             |
| t <sub>DHR</sub> | Read data hold time                                             | 0       | -       | 25      | ns   |             |
| t <sub>DHW</sub> | Write data hold time                                            | 0       | -       | -       | ns   |             |
| t <sub>AS</sub>  | Address setup time                                              | 20      | -       | -       | ns   |             |
| t <sub>AH</sub>  | Address hold time                                               | 5       | -       | -       | ns   |             |
| t <sub>DAS</sub> | Delay time, DS to AS rise                                       | 10      | -       | -       | ns   |             |
| t <sub>ASW</sub> | Pulse width, AS high                                            | 30      | -       | -       | ns   |             |
| t <sub>ASD</sub> | Delay time, AS to DS rise ( $\overline{RD}/\overline{WR}$ fall) | 35      | -       | -       | ns   |             |
| t <sub>OD</sub>  | Output data delay time from DS rise (RD fall)                   | -       | -       | 50      | ns   |             |
| t <sub>DW</sub>  | Write data setup time                                           | 30      | -       | -       | ns   |             |
| t <sub>BUC</sub> | Delay time before update cycle                                  | -       | 244     | -       | μs   |             |
| t <sub>PI</sub>  | Periodic interrupt time interval                                | -       | -       | -       | -    | See Table 3 |
| t <sub>UC</sub>  | Time of update cycle                                            | -       | 1       | -       | μs   |             |

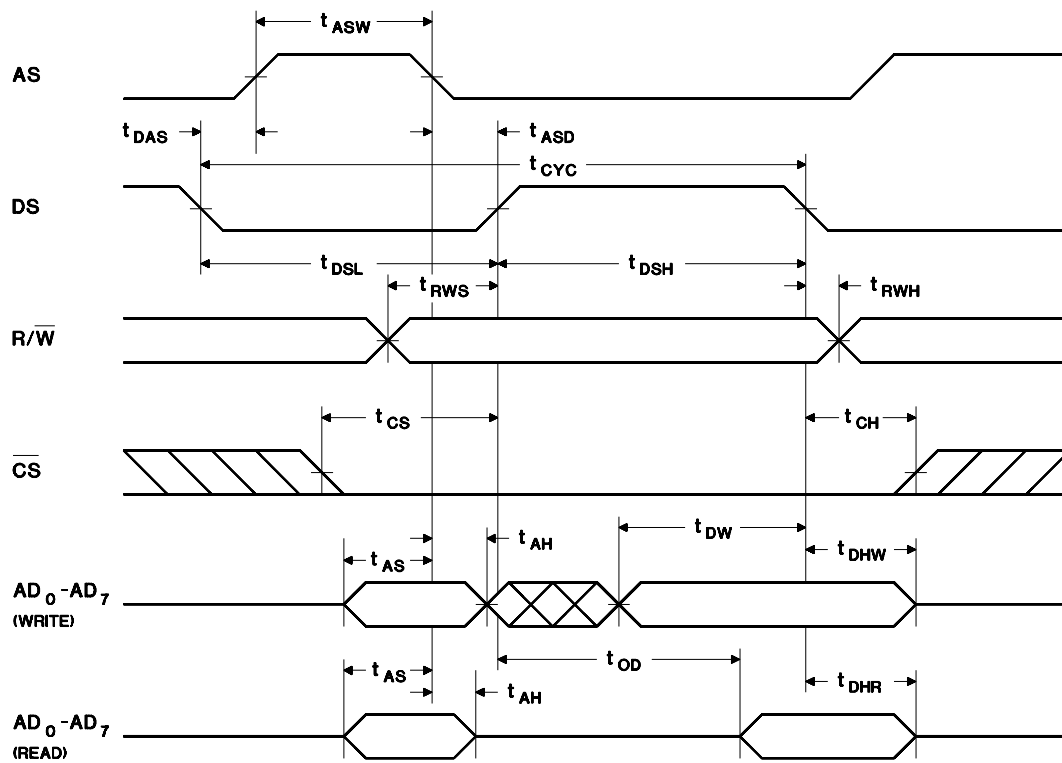
## bq3285E/L

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### Read/Write Timing—bq3285L ( $T_A = T_{OPR}$ , $V_{CC} = 3.15V \pm 0.45V$ )

| Symbol           | Parameter                                                       | Minimum | Typical | Maximum | Unit    | Notes       |
|------------------|-----------------------------------------------------------------|---------|---------|---------|---------|-------------|
| t <sub>CYC</sub> | Cycle time                                                      | 270     | -       | -       | ns      |             |
| t <sub>DSL</sub> | DS low or $\overline{RD}/\overline{WR}$ high time               | 135     | -       | -       | ns      |             |
| t <sub>DSH</sub> | DS high or $\overline{RD}/\overline{WR}$ low time               | 90      | -       | -       | ns      |             |
| t <sub>RWH</sub> | $R/\overline{W}$ hold time                                      | 0       | -       | -       | ns      |             |
| t <sub>RWS</sub> | $R/\overline{W}$ setup time                                     | 15      | -       | -       | ns      |             |
| t <sub>CS</sub>  | Chip select setup time                                          | 8       | -       | -       | ns      |             |
| t <sub>CH</sub>  | Chip select hold time                                           | 0       | -       | -       | ns      |             |
| t <sub>DHR</sub> | Read data hold time                                             | 0       | -       | 40      | ns      |             |
| t <sub>DHW</sub> | Write data hold time                                            | 0       | -       | -       | ns      |             |
| t <sub>AS</sub>  | Address setup time                                              | 30      | -       | -       | ns      |             |
| t <sub>AH</sub>  | Address hold time                                               | 15      | -       | -       | ns      |             |
| t <sub>DAS</sub> | Delay time, DS to AS rise                                       | 15      | -       | -       | ns      |             |
| t <sub>ASW</sub> | Pulse width, AS high                                            | 50      | -       | -       | ns      |             |
| t <sub>ASD</sub> | Delay time, AS to DS rise ( $\overline{RD}/\overline{WR}$ fall) | 55      | -       | -       | ns      |             |
| t <sub>OD</sub>  | Output data delay time from DS rise (RD fall)                   | -       | -       | 100     | ns      |             |
| t <sub>DW</sub>  | Write data setup time                                           | 50      | -       | -       | ns      |             |
| t <sub>BUC</sub> | Delay time before update cycle                                  | -       | 244     | -       | $\mu s$ |             |
| t <sub>PI</sub>  | Periodic interrupt time interval                                | -       | -       | -       | -       | See Table 3 |
| t <sub>UC</sub>  | Time of update cycle                                            | -       | 1       | -       | $\mu s$ |             |

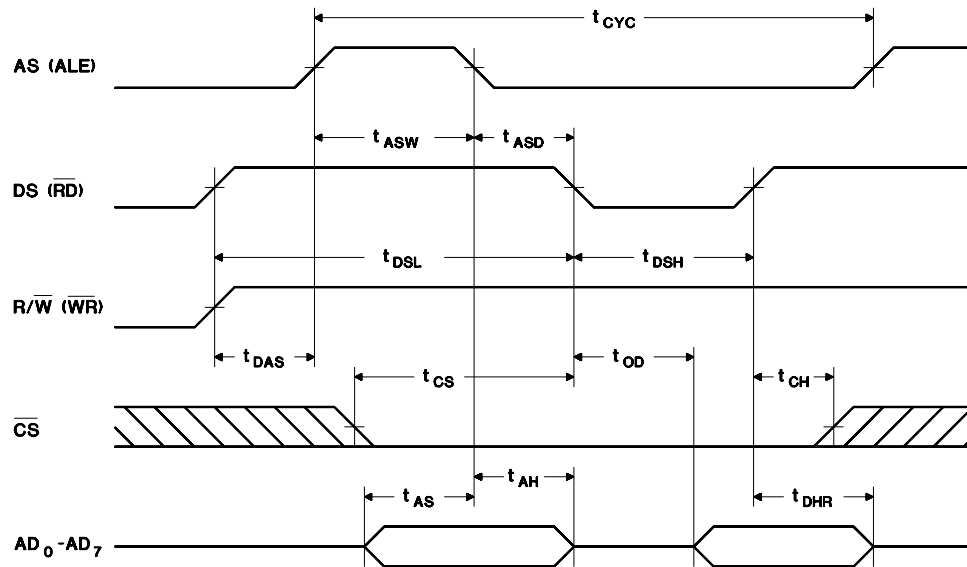
## Motorola Bus Read/Write Timing—bq3285E/L



RC-4

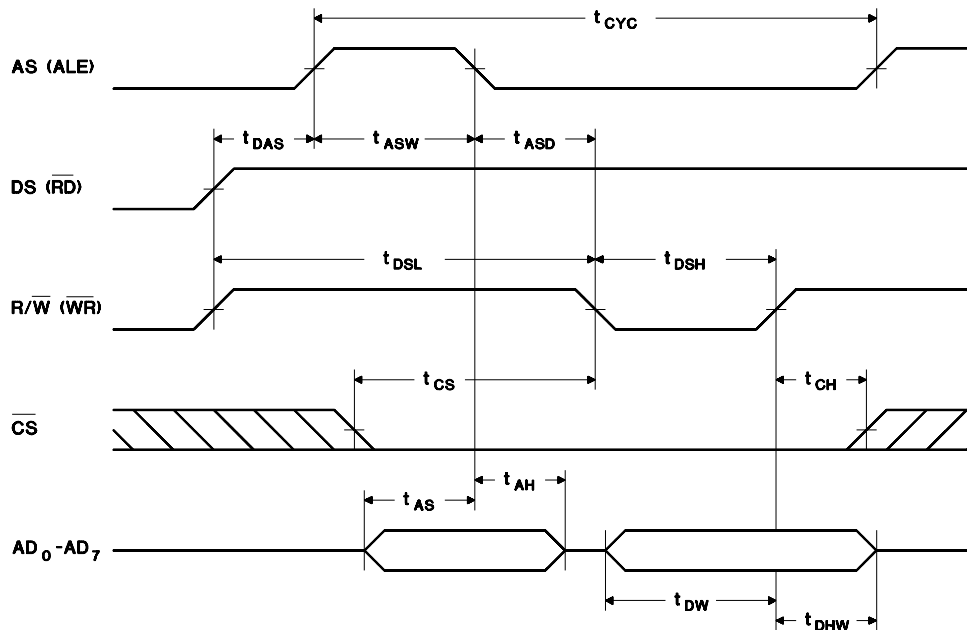
## bq3285E/L

### Intel Bus Read Timing—bq3285E/L



RC-5

### Intel Bus Write Timing—bq3285E/L

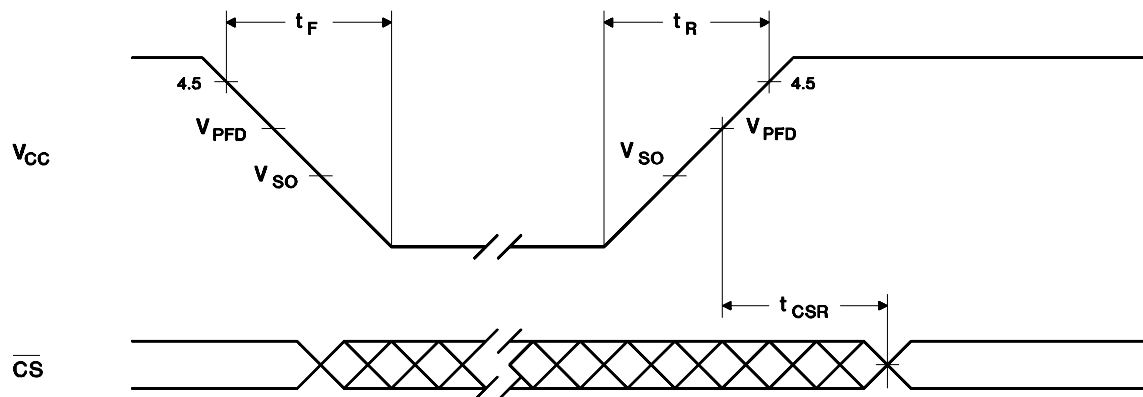


WC-5

**Power-Down/Power-Up Timing—bq3285E** ( $T_A = T_{OPR}$ )

| Symbol    | Parameter                                  | Minimum | Typical | Maximum | Unit    | Conditions                                                                    |
|-----------|--------------------------------------------|---------|---------|---------|---------|-------------------------------------------------------------------------------|
| $t_F$     | $V_{CC}$ slew from 4.5V to 0V              | 300     | -       | -       | $\mu s$ |                                                                               |
| $t_R$     | $V_{CC}$ slew from 0V to 4.5V              | 100     | -       | -       | $\mu s$ |                                                                               |
| $t_{CSR}$ | $\overline{CS}$ at $V_{IH}$ after power-up | 20      | -       | 200     | ms      | Internal write-protection period after $V_{CC}$ passes $V_{PFD}$ on power-up. |

**Caution:** Negative undershoots below the absolute maximum rating of -0.3V in battery-backup mode may affect data integrity.

**Power-Down/Power-Up Timing—bq3285E**

PD-4A

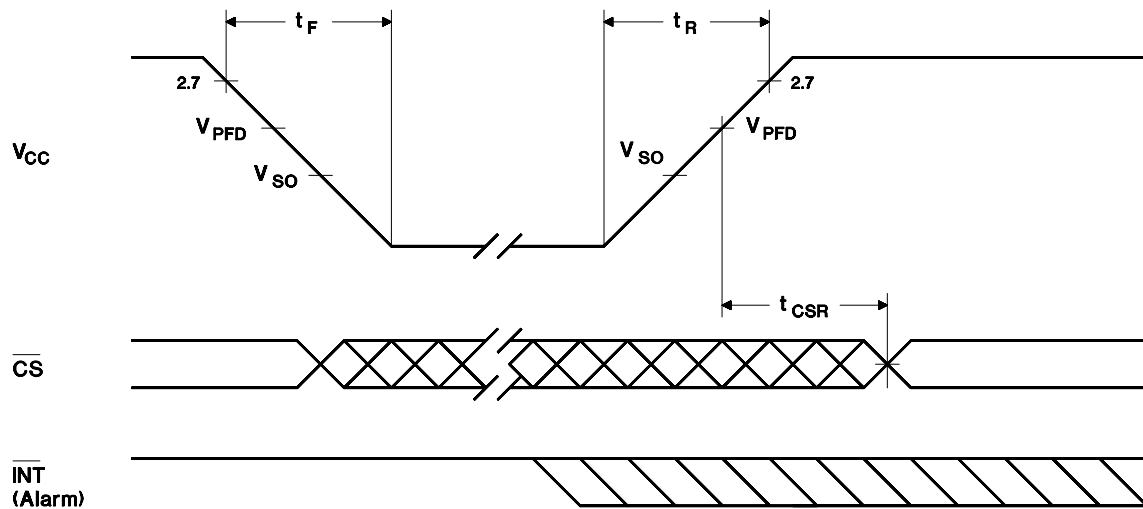
## bq3285E/L

### Power-Down/Power-Up Timing—bq3285L ( $T_A = T_{OPR}$ )

| Symbol    | Parameter                                  | Minimum | Typical | Maximum | Unit    | Conditions                                                                    |
|-----------|--------------------------------------------|---------|---------|---------|---------|-------------------------------------------------------------------------------|
| $t_F$     | $V_{CC}$ slew from 2.7V to 0V              | 300     | -       | -       | $\mu s$ |                                                                               |
| $t_R$     | $V_{CC}$ slew from 0V to 2.7V              | 100     | -       | -       | $\mu s$ |                                                                               |
| $t_{CSR}$ | $\overline{CS}$ at $V_{IH}$ after power-up | 20      | -       | 200     | ms      | Internal write-protection period after $V_{CC}$ passes $V_{PFD}$ on power-up. |

**Caution:** Negative undershoots below the absolute maximum rating of -0.3V in battery-backup mode may affect data integrity.

### Power-Down/Power-Up Timing—bq3285L

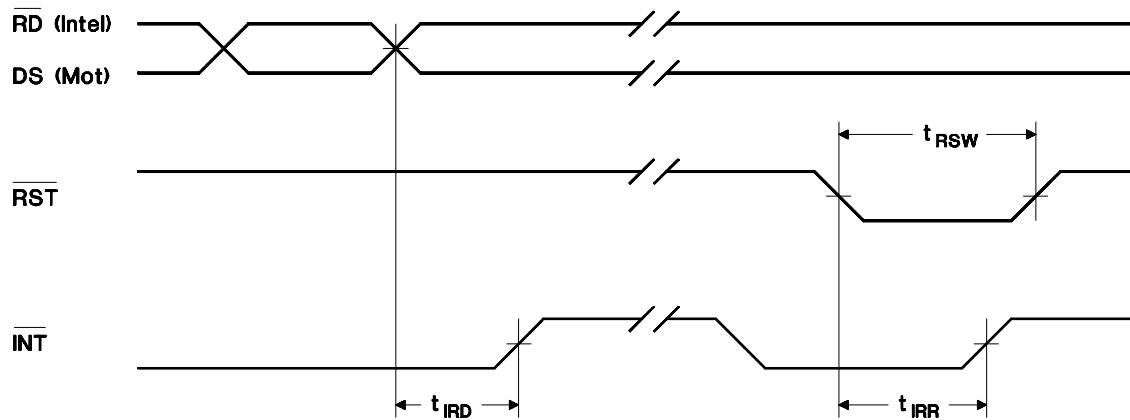


PD-5

### Interrupt Delay Timing—bq3285E/L ( $T_A = T_{OPR}$ )

| Symbol    | Parameter                                      | Minimum | Typical | Maximum | Unit    |
|-----------|------------------------------------------------|---------|---------|---------|---------|
| $t_{RSW}$ | Reset pulse width                              | 5       | -       | -       | $\mu s$ |
| $t_{IRR}$ | $\overline{INT}$ release from $\overline{RST}$ | -       | -       | 2       | $\mu s$ |
| $t_{IRD}$ | $\overline{INT}$ release from DS               | -       | -       | 2       | $\mu s$ |

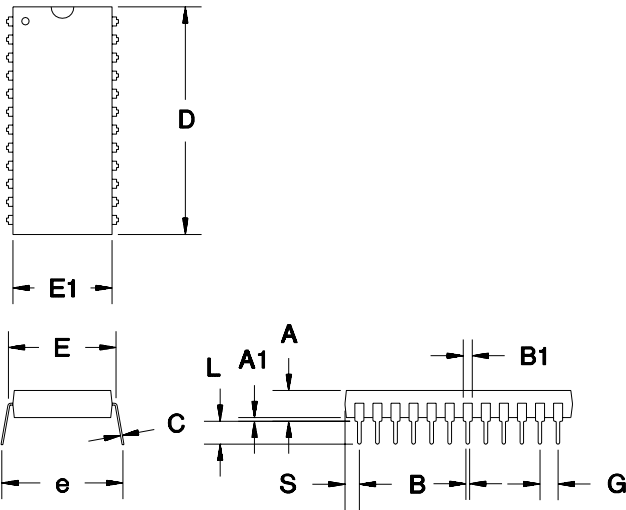
### Interrupt Delay Timing—bq3285E/L



INT-1

**bq3285E/L**

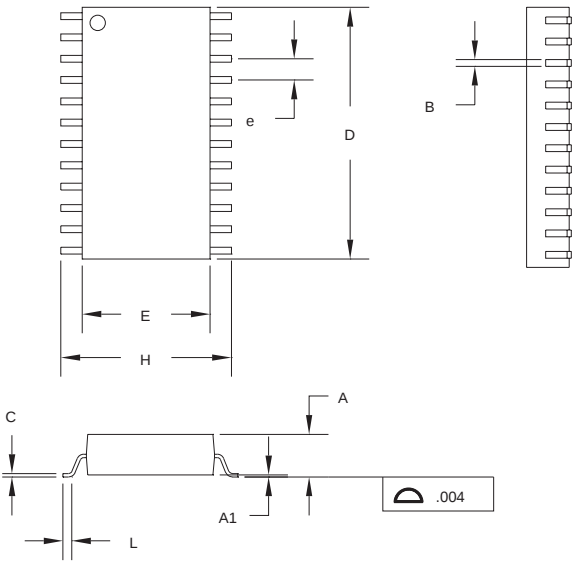
**24-Pin DIP (P)**



**24-Pin DIP (0.600" DIP)**

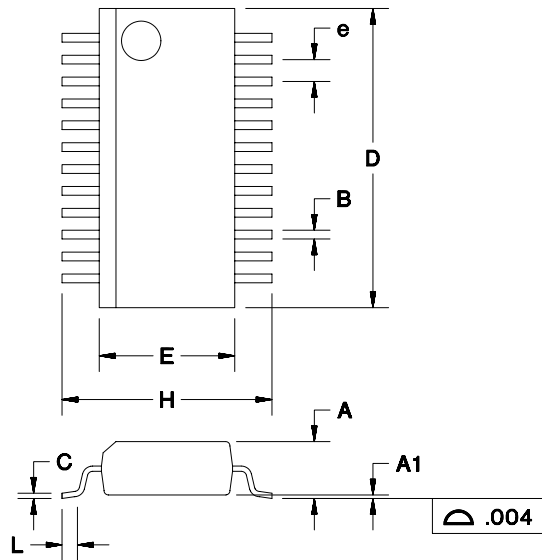
| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min.   | Max.  | Min.        | Max.  |
| A         | 0.160  | 0.190 | 4.06        | 4.83  |
| A1        | 0.015  | 0.040 | 0.38        | 1.02  |
| B         | 0.015  | 0.022 | 0.38        | 0.56  |
| B1        | 0.045  | 0.065 | 1.14        | 1.65  |
| C         | 0.008  | 0.013 | 0.20        | 0.33  |
| D         | 1.240  | 1.280 | 31.50       | 32.51 |
| E         | 0.600  | 0.625 | 15.24       | 15.88 |
| E1        | 0.530  | 0.570 | 13.46       | 14.48 |
| e         | 0.600  | 0.670 | 15.24       | 17.02 |
| G         | 0.090  | 0.110 | 2.29        | 2.79  |
| L         | 0.115  | 0.150 | 2.92        | 3.81  |
| S         | 0.070  | 0.090 | 1.78        | 2.29  |

**24-Pin SOIC (S)**



**24-Pin S (0.300" SOIC)**

| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min.   | Max.  | Min.        | Max.  |
| A         | 0.095  | 0.105 | 2.41        | 2.67  |
| A1        | 0.004  | 0.012 | 0.10        | 0.30  |
| B         | 0.013  | 0.020 | 0.33        | 0.51  |
| C         | 0.008  | 0.013 | 0.20        | 0.33  |
| D         | 0.600  | 0.615 | 15.24       | 15.62 |
| E         | 0.290  | 0.305 | 7.37        | 7.75  |
| e         | 0.045  | 0.055 | 1.14        | 1.40  |
| H         | 0.395  | 0.415 | 10.03       | 10.54 |
| L         | 0.020  | 0.040 | 0.51        | 1.02  |

**24-Pin SSOP (SS)****24-Pin SS (0.150" SSOP)**

| Dimension | Inches   |       | Millimeters |      |
|-----------|----------|-------|-------------|------|
|           | Min.     | Max.  | Min.        | Max. |
| A         | 0.061    | 0.068 | 1.55        | 1.73 |
| A1        | 0.004    | 0.010 | 0.10        | 0.25 |
| B         | 0.008    | 0.012 | 0.20        | 0.30 |
| C         | 0.007    | 0.010 | 0.18        | 0.25 |
| D         | 0.337    | 0.344 | 8.56        | 8.74 |
| E         | 0.150    | 0.157 | 3.81        | 3.99 |
| e         | .025 BSC |       | 0.64 BSC    |      |
| H         | 0.230    | 0.244 | 5.84        | 6.20 |
| L         | 0.016    | 0.035 | 0.41        | 0.89 |

## bq3285E/L

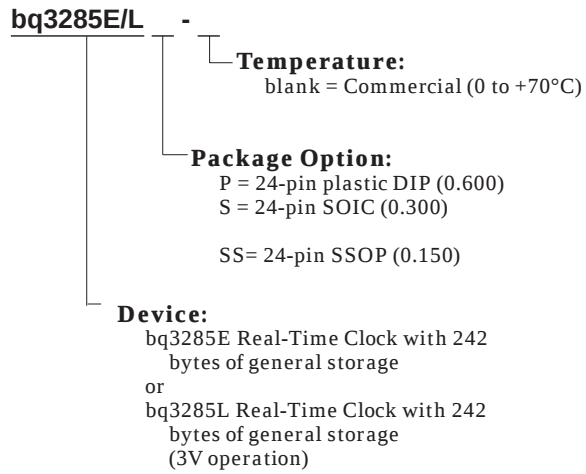
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### Data Sheet Revision History

| Change No. | Page No.  | Description                     | Nature of Change                                       |
|------------|-----------|---------------------------------|--------------------------------------------------------|
| 1          | 8         | Register C, bit 2               | Was 0; is na (not affected)                            |
| 1          | 18        | Output data delay time $t_{OD}$ | Was 80 ns max; is 100 ns max                           |
| 2          | 1, 24, 26 | Package option change           | Lst time buy for some package options.                 |
| 3          | 1, 24, 26 | Package option change           | Removed PLCC and added industrial SSOP package options |
| 4          | 1, 11     | Package option change           | Industrial package option removed                      |

**Note:** Change 1 = Jan. 1995 B "Final" changes from Dec. 1993 A "Preliminary".  
Change 2 = Jan. 1999 C changes from Jan. 1995 B  
Change 3 = Apr. 1999 D changes from Jan. 1999 C.  
Change 4 = May 2004 (SLUS004A) changes from Apr. 1999 D

## Ordering Information



bq3285L only available in 24-pin SSOP (0.150).

## PACKAGING INFORMATION

| Orderable Device | Status <sup>(1)</sup> | Package Type  | Package Drawing | Pins | Package Qty | Eco Plan <sup>(2)</sup> | Lead/Ball Finish | MSL Peak Temp <sup>(3)</sup>              |
|------------------|-----------------------|---------------|-----------------|------|-------------|-------------------------|------------------|-------------------------------------------|
| BQ3285EP         | ACTIVE                | PDIP          | N               | 24   | 15          | None                    | A42 SNPB         | Level-NA-NA-NA                            |
| BQ3285ES         | ACTIVE                | SOIC          | DW              | 24   | 25          | None                    | CU SNPB          | Level-1-220C-UNLIM                        |
| BQ3285ESS        | ACTIVE                | SSOP/<br>QSOP | DBQ             | 24   | 50          | Pb-Free<br>(RoHS)       | CU NIPDAU        | Level-2-260C-1YEAR/<br>Level-1-220C-UNLIM |
| BQ3285ESSTR      | ACTIVE                | SSOP/<br>QSOP | DBQ             | 24   | 2500        | Pb-Free<br>(RoHS)       | CU NIPDAU        | Level-2-260C-1YEAR/<br>Level-1-220C-UNLIM |
| BQ3285ESTR       | ACTIVE                | SOIC          | DW              | 24   | 2000        | None                    | CU SNPB          | Level-1-220C-UNLIM                        |
| BQ3285LSS        | OBSOLETE              | SSOP/<br>QSOP | DBQ             | 24   |             | None                    | Call TI          | Call TI                                   |
| BQ3285LSSTR      | OBSOLETE              | SSOP          | DB              | 24   |             | None                    | Call TI          | Call TI                                   |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - May not be currently available - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**None:** Not yet available Lead (Pb-Free).

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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